# MMBTA92LT1G, MMBTA93LT1G

# High Voltage Transistors PNP Silicon

### Features

• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### MAXIMUM RATINGS

Rating	Symbol	92	93	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	-300	-200	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	-300	-200	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	-5.0	-5.0	Vdc
Collector Current — Continuous	Ι <sub>C</sub>	-500		mAdc

### **DEVICE MARKING**

MMBTA92LT1 = 2D; MMBTA93LT1 = 2E

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note 1) $T_A = 25^{\circ}C$	PD	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation (Note 2) Alumina Substrate, <sup>(2)</sup> $T_A = 25^{\circ}C$	PD	300	mW
Derate above $25^{\circ}$ C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

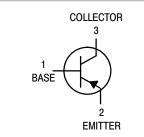
1.  $FR-5 = 1.0 \times 0.75 \times 0.062$  in.

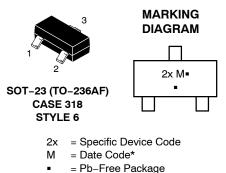
2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



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(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBTA92LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBTA92LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
MMBTA93LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

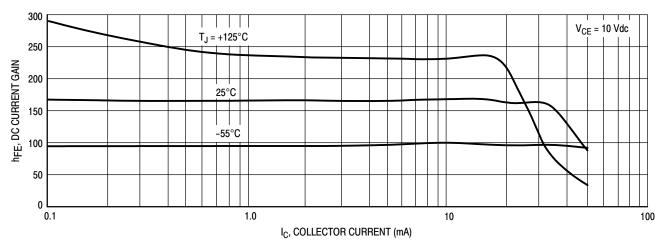
+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

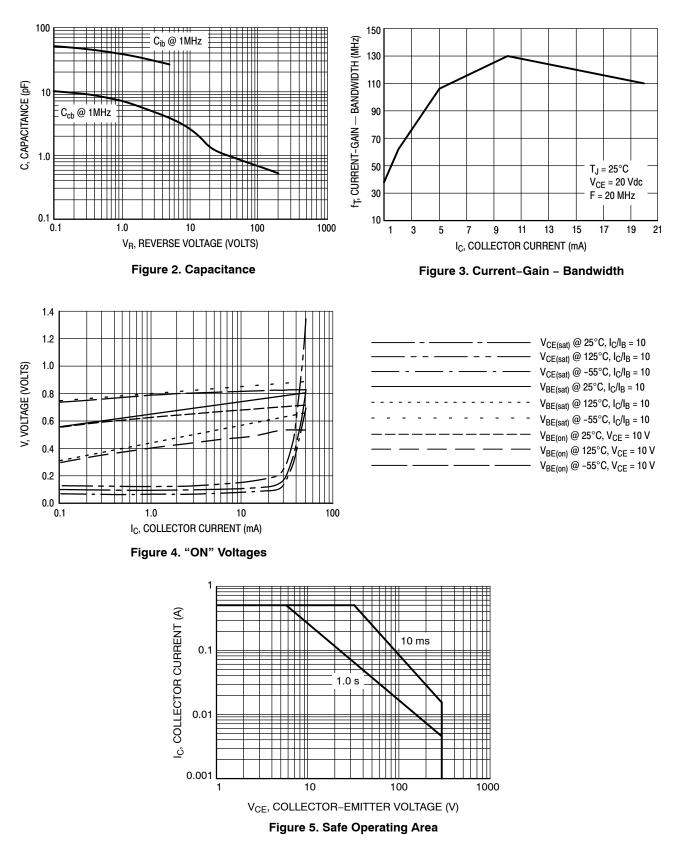
Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 3) $(I_C = -1.0 \text{ mAdc}, I_B = 0)$	MMBTA92 MMBTA93	V <sub>(BR)CEO</sub>	-300 -200		Vdc
Collector – Base Breakdown Voltage ( $I_C = -100 \ \mu Adc$ , $I_E = 0$ )	MMBTA92 MMBTA93	V <sub>(BR)CBO</sub>	-300 -200		Vdc
Emitter – Base Breakdown Voltage ( $I_E = -100 \ \mu Adc$ , $I_C = 0$ )		V <sub>(BR)EBO</sub>	-5.0	-	Vdc
Collector Cutoff Current ( $V_{CB} = -200 \text{ Vdc}, I_E = 0$ ) ( $V_{CB} = -160 \text{ Vdc}, I_E = 0$ )	MMBTA92 MMBTA93	I <sub>CBO</sub>	-	-0.25 -0.25	μAdc
Emitter Cutoff Current ( $V_{EB} = -3.0 \text{ Vdc}, I_C = 0$ )		I <sub>EBO</sub>	-	-0.1	μAdc
ON CHARACTERISTICS (Note 3)					
DC Current Gain ( $I_C = -1.0 \text{ mAdc}$ , $V_{CE} = -10 \text{ Vdc}$ ) ( $I_C = -10 \text{ mAdc}$ , $V_{CE} = -10 \text{ Vdc}$ )	Both Types Both Types	h <sub>FE</sub>	25 40		-
(I <sub>C</sub> = -30 mAdc, $V_{CE}$ = -10 Vdc)	MMBTA92 MMBTA93		25 25		
Collector – Emitter Saturation Voltage ( $I_C = -20$ mAdc, $I_B = -2.0$ mAdc)	MMBTA92 MMBTA93	V <sub>CE(sat)</sub>		-0.5 -0.5	Vdc
Base-Emitter Saturation Voltage (I <sub>C</sub> = -20 mAdc, I <sub>B</sub> = -2.0 mAdc)		V <sub>BE(sat)</sub>	_	-0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS			-	•	
Current-Gain — Bandwidth Product ( $I_C = -10$ mAdc, $V_{CE} = -20$ Vdc, f = 100 MHz)		f <sub>T</sub>	50	_	MHz
Collector-Base Capacitance ( $V_{CB}$ = -20 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	MMBTA92 MMBTA93	C <sub>cb</sub>	-	6.0 8.0	pF

3. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.



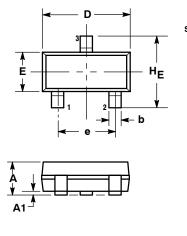


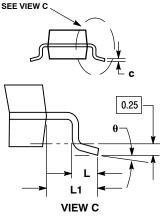
## MMBTA92LT1G, MMBTA93LT1G



### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AP





NOTES:

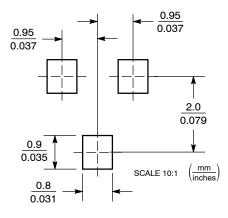
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM
- THICKNESS OF BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

				i			
	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.89	1.00	1.11	0.035	0.040	0.044	
A1	0.01	0.06	0.10	0.001	0.002	0.004	
b	0.37	0.44	0.50	0.015	0.018	0.020	
c	0.09	0.13	0.18	0.003	0.005	0.007	
D	2.80	2.90	3.04	0.110	0.114	0.120	
E	1.20	1.30	1.40	0.047	0.051	0.055	
е	1.78	1.90	2.04	0.070	0.075	0.081	
Г	0.10	0.20	0.30	0.004	0.008	0.012	
L1	0.35	0.54	0.69	0.014	0.021	0.029	
ΗE	2.10	2.40	2.64	0.083	0.094	0.104	
θ	0°		10°	0°		10°	

STYLE 6: PIN 1. BASE

2. EMITTER
 3. COLLECTOR

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